
HD74LV165A

Parallel-Load 8-bit Shift Register

HITACHI

ADE-205-267 (Z)
1st Edition
March 1999

Description

The HD74LV165A is 8-bit serial shift register shifts data from Q_A to Q_H when clocked. Parallel inputs to each stage are enabled by a low level at the Shift/Load input. Also included is a gated clock input and a complementary output from the eighth bit.

Clocking is accomplished through a 2-input NOR gate permitting one input to be used as a clock inhibit function. Holding either of the clock inputs high inhibits clocking, and high enables the other clock input. Data transfer occurs on the positive going edge of the clock. Parallel loading is inhibited as long as the Shift/Load input is high. When taken low, data at the parallel inputs is loaded directly into the register independent of the state of the clock.

Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

Features

- $V_{CC} = 2.0\text{ V}$ to 5.5 V operation
- All inputs V_{IH} (Max.) = 5.5 V (@ $V_{CC} = 0\text{ V}$ to 5.5 V)
- All outputs V_O (Max.) = 5.5 V (@ $V_{CC} = 0\text{ V}$)
- Typical V_{OL} ground bounce $< 0.8\text{ V}$ (@ $V_{CC} = 3.3\text{ V}$, $T_a = 25^\circ\text{C}$)
- Typical V_{OH} undershoot $> 2.3\text{ V}$ (@ $V_{CC} = 3.3\text{ V}$, $T_a = 25^\circ\text{C}$)
- Output current $\pm 6\text{ mA}$ (@ $V_{CC} = 3.0\text{ V}$ to 3.6 V), $\pm 12\text{ mA}$ (@ $V_{CC} = 4.5\text{ V}$ to 5.5 V)

HD74LV165A

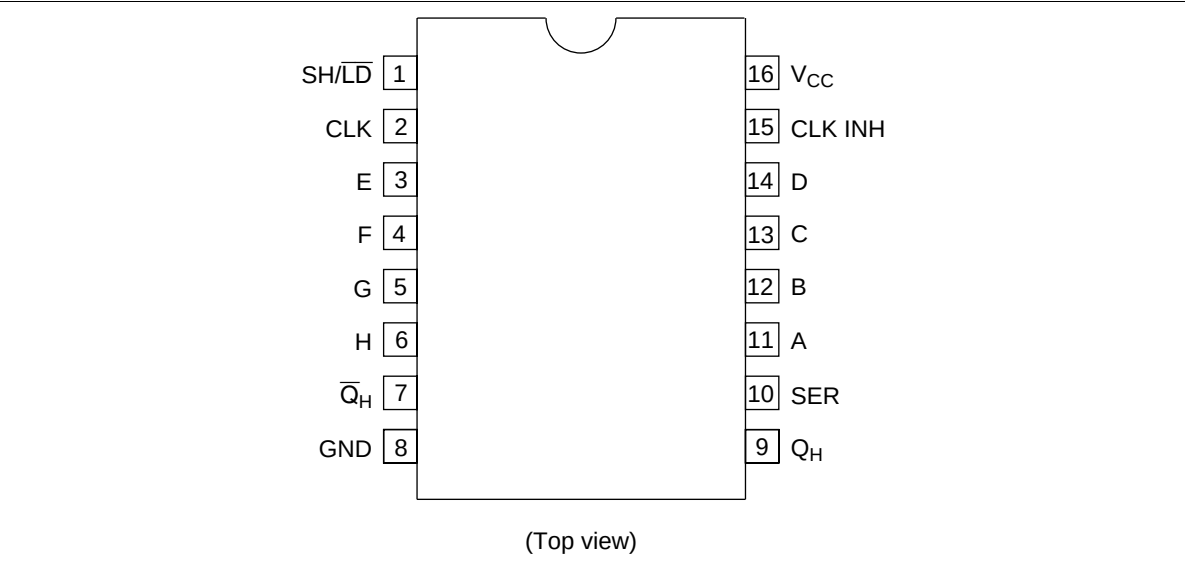
Function Table

Inputs					Internal Outputs		Output
SH/LD	CLK INH	CLK	SER	A ... H	QA	QB	QH
L	X	X	X	a ... h	a	b	h
H	L	↑	H	X	H	Q _{An}	Q _{Gn}
H	L	↑	L	X	L	Q _{An}	Q _{Gn}
H	H	X	X	X	Q _{A0}	Q _{B0}	Q _{H0}
H	X	H	X	X	Q _{A0}	Q _{B0}	Q _{H0}
H	↑	L	H	X	H	Q _{An}	Q _{Gn}
H	↑	L	L	X	L	Q _{An}	Q _{Gn}

Note:

- H: High level
- L: Low level
- ↑: Low to high transition
- X: Immaterial
- a ... h: Parallel data
- Q_{A0} ... Q_{H0}: Outputs remain unchanged.
- Q_{An} ... Q_{Gn}: Data shifted from the previous stage on a positive edge at the clock input.

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V_{CC}	−0.5 to 7.0	V	
Input voltage range* ¹	V_I	−0.5 to 7.0	V	
Output voltage range* ^{1, 2}	V_O	−0.5 to $V_{CC} + 0.5$ −0.5 to 7.0	V	Output: H or L V_{CC} : OFF
Input clamp current	I_{IK}	−20	mA	$V_I < 0$
Output clamp current	I_{OK}	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I_O	±25	mA	$V_O = 0$ to V_{CC}
Continuous current through V_{CC} or GND	I_{CC} or I_{GND}	±50	mA	
Maximum power dissipation at $T_a = 25^{\circ}\text{C}$ (in still air)* ³	P_T	785 500	mW	SOP TSSOP
Storage temperature	T_{stg}	−65 to 150	$^{\circ}\text{C}$	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

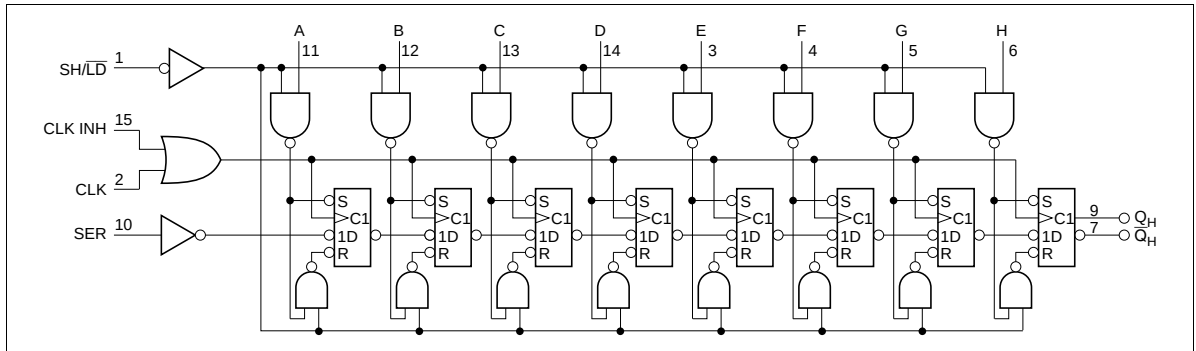
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

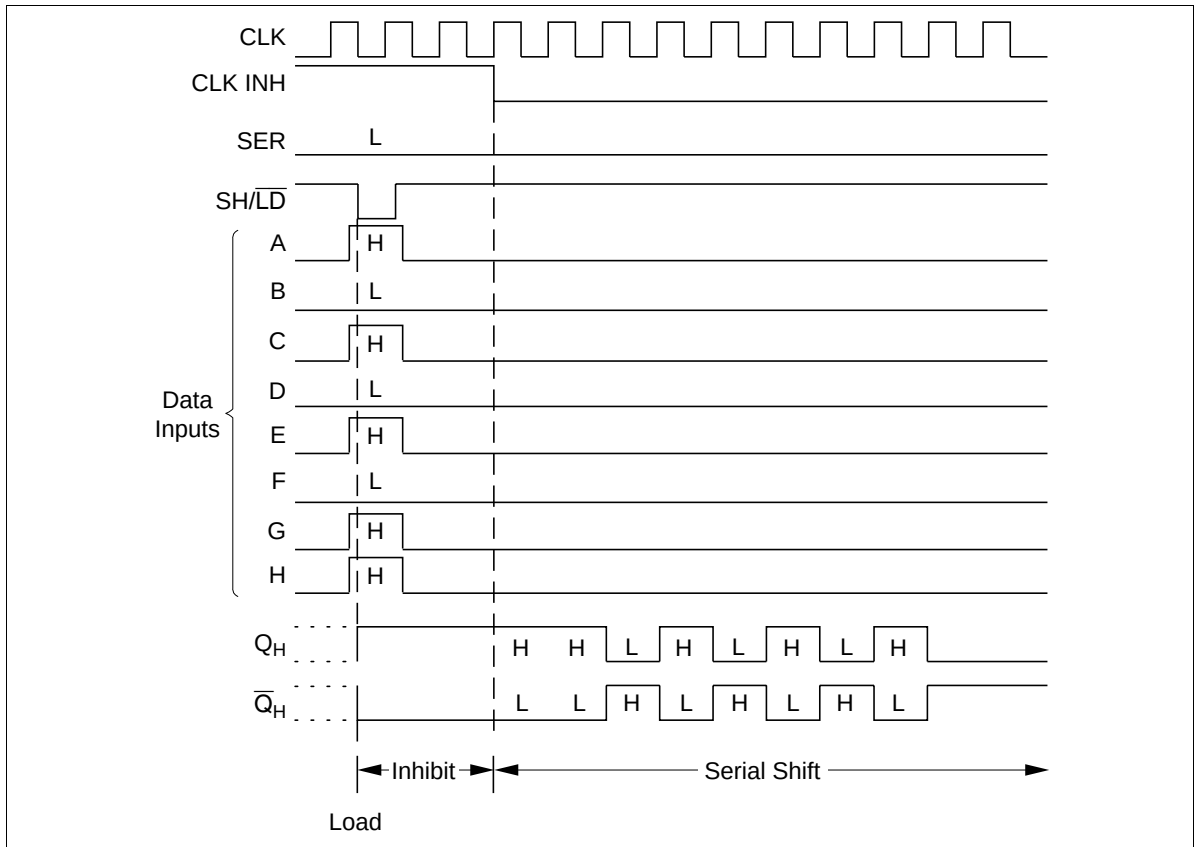
Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{CC}	2.0	5.5	V	
Input voltage range	V _I	0	5.5	V	
Output voltage range	V _O	0	V _{CC}	V	H or L
Output current	I _{OH}	—	−50	μA	V _{CC} = 2.0 V
		—	−2	mA	V _{CC} = 2.3 to 2.7 V
		—	−6		V _{CC} = 3.0 to 3.6 V
		—	−12		V _{CC} = 4.5 to 5.5 V
	I _{OL}	—	50	μA	V _{CC} = 2.0 V
		—	2	mA	V _{CC} = 2.3 to 2.7 V
		—	6		V _{CC} = 3.0 to 3.6 V
		—	12		V _{CC} = 4.5 to 5.5 V
Input transition rise or fall rate	Δt / Δv	0	200	ns/V	V _{CC} = 2.3 to 2.7 V
		0	100		V _{CC} = 3.0 to 3.6 V
		0	20		V _{CC} = 4.5 to 5.5 V
Operating free-air temperature	Ta	−40	85	°C	

Note: Unused or floating inputs must be held high or low.

Logic Diagram



Timing Diagram



DC Electrical Characteristics

• Ta = -40 to 85°C

Item	Symbol	V _{CC} (V)*	Min	Typ	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.0	1.5	—	—	V	
		2.3 to 2.7	V _{CC} × 0.7	—	—		
		3.0 to 3.6	V _{CC} × 0.7	—	—		
		4.5 to 5.5	V _{CC} × 0.7	—	—		
	V _{IL}	2.0	—	—	0.5		
		2.3 to 2.7	—	—	V _{CC} × 0.3		
		3.0 to 3.6	—	—	V _{CC} × 0.3		
		4.5 to 5.5	—	—	V _{CC} × 0.3		
Output voltage	V _{OH}	Min to Max	V _{CC} - 0.1	—	—	V	I _{OL} = -50 μA
		2.3	2.0	—	—		I _{OL} = -2 mA
		3.0	2.48	—	—		I _{OL} = -6 mA
		4.5	3.8	—	—		I _{OL} = -12 mA
	V _{OL}	Min to Max	—	—	0.1		I _{OL} = 50 μA
		2.3	—	—	0.4		I _{OL} = 2 mA
		3.0	—	—	0.44		I _{OL} = 6 mA
		4.5	—	—	0.55		I _{OL} = 12 mA
Input current	I _{IN}	0 to 5.5	—	—	±1	μA	V _I = 5.5 V or GND
Quiescent supply current	I _{CC}	5.5	—	—	20	μA	V _I = V _{CC} or GND, I _O = 0
Output leakage current	I _{OFF}	0	—	—	5	μA	V _I or V _O = 0 V to 5.5 V
Input capacitance	C _{IN}	3.3	—	1.7	—	pF	V _I = V _{CC} or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

- $V_{CC} = 2.5 \pm 0.2 \text{ V}$

		Ta = 25°C			Ta = −40 to 85°C					
Item	Symbol	Min	Typ	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Maximum clock frequency	fmax	50	80	—	45	—	MHz	C _L = 15 pF		
		40	65	—	35	—		C _L = 50 pF		
Propagation delay time	t _{PLH} /t _{PHL}	—	13.1	21.5	1.0	23.5	ns	C _L = 15 pF	SH/ $\overline{LD}$	Q _H or $\overline{Q}_H$
		—	16.1	25.1	1.0	28.0		C _L = 50 pF		
		—	12.2	19.8	1.0	22.0		C _L = 15 pF	CLK	
		—	15.3	23.3	1.0	26.0		C _L = 50 pF		
		—	12.9	21.7	1.0	24.0		C _L = 15 pF	H	
		—	15.9	25.3	1.0	28.0		C _L = 50 pF		
Setup time	t _{su}	7.0	—	—	7.0	—	ns		CLK INH before CLK ↑	
		11.5	—	—	12.0	—			data before SH/ $\overline{LD}$ ↑	
		7.0	—	—	8.5	—	ns		SH/ $\overline{LD}$ high before CLK ↑	
		8.5	—	—	9.5	—			SER before CLK ↑	
Hold time	t _h	0.0	—	—	0.5	—	ns		PAR data after SH/ $\overline{LD}$ ↑	
		−1.0	—	—	0.0	—			SER data after CLK ↑	
		0.0	—	—	0.0	—			SH/ $\overline{LD}$ high after CLK ↑	
Pulse width	t _w	11.0	—	—	13.0	—	ns		SH/ $\overline{LD}$ low	
		8.5	—	—	9.0	—			CLK H or L	

Switching Characteristics (cont)

• $V_{CC} = 3.3 \pm 0.3 \text{ V}$

Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Typ	Max	Min	Max				
Maximum clock frequency	fmax	65	115	—	55	—	MHz	$C_L = 15 \text{ pF}$		
		60	90	—	50	—		$C_L = 50 \text{ pF}$		
Propagation delay time	t_{PLH}/t_{PHL}	—	9.1	15.8	1.0	18.5	ns	$C_L = 15 \text{ pF}$	SH/ $\overline{LD}$	Q_H or $\overline{Q}_H$
		—	11.3	19.3	1.0	22.0		$C_L = 50 \text{ pF}$		
		—	8.6	15.4	1.0	18.0		$C_L = 15 \text{ pF}$	CLK	
		—	10.9	18.9	1.0	21.5		$C_L = 50 \text{ pF}$		
		—	8.9	14.1	1.0	16.5		$C_L = 15 \text{ pF}$	H	
		—	11.1	17.6	1.0	20.0		$C_L = 50 \text{ pF}$		
Setup time	t_{su}	5.0	—	—	5.0	—	ns		CLK INH before CLK $\uparrow$	
		7.5	—	—	8.5	—			data before SH/ $\overline{LD}$ $\uparrow$	
		5.0	—	—	6.0	—	ns		SH/ $\overline{LD}$ high before CLK $\uparrow$	
		5.0	—	—	6.0	—			SER before CLK $\uparrow$	
Hold time	t_h	0.5	—	—	0.5	—	ns		PAR data after SH/ $\overline{LD}$ $\uparrow$	
		0.0	—	—	0.0	—			SER data after CLK $\uparrow$	
		0.0	—	—	0.0	—			SH/ $\overline{LD}$ high after CLK $\uparrow$	
Pulse width	t_w	7.5	—	—	9.0	—	ns		SH/ $\overline{LD}$ low	
		6.0	—	—	7.0	—			CLK H or L	

Switching Characteristics (cont)

• $V_{CC} = 5.0 \pm 0.5 \text{ V}$

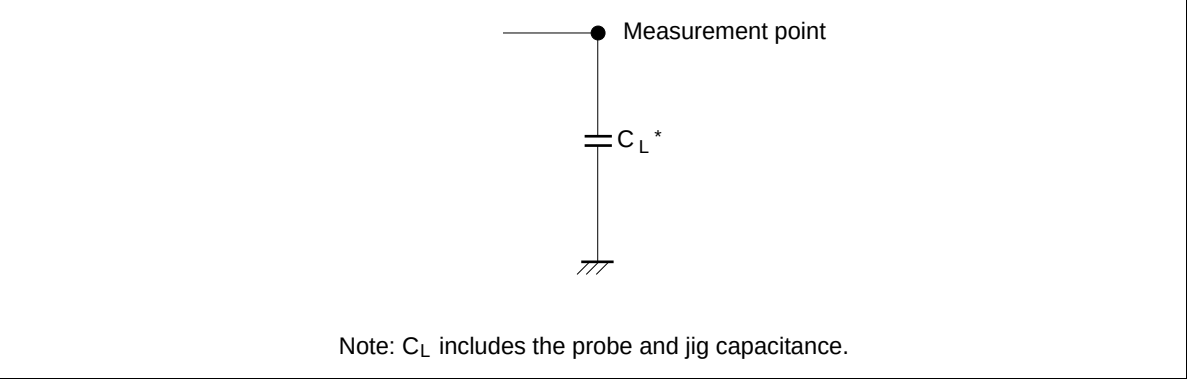
Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Typ	Max	Min	Max				
Maximum clock frequency	fmax	110	165	—	90	—	MHz	$C_L = 15 \text{ pF}$		
		95	125	—	85	—		$C_L = 50 \text{ pF}$		
Propagation delay time	t_{PLH}/t_{PHL}	—	6.0	9.9	1.0	11.5	ns	$C_L = 15 \text{ pF}$	SH/ $\overline{LD}$	Q_H or $\overline{Q}_H$
		—	7.7	11.9	1.0	13.5		$C_L = 50 \text{ pF}$		
		—	6.0	9.9	1.0	11.5		$C_L = 15 \text{ pF}$	CLK	
		—	7.7	11.9	1.0	13.5		$C_L = 50 \text{ pF}$		
		—	6.0	9.0	1.0	10.5		$C_L = 15 \text{ pF}$	H	
		—	7.6	11.0	1.0	12.5		$C_L = 50 \text{ pF}$		
Setup time	t_{su}	3.5	—	—	3.5	—	ns		CLK INH before CLK $\uparrow$	
		5.0	—	—	5.0	—			data before SH/ $\overline{LD}$ $\uparrow$	
		4.0	—	—	4.0	—	ns		SH/ $\overline{LD}$ high before CLK $\uparrow$	
		4.0	—	—	4.0	—			SER before CLK $\uparrow$	
Hold time	t_h	1.0	—	—	1.0	—	ns		PAR data after SH/ $\overline{LD}$ $\uparrow$	
		0.5	—	—	0.5	—			SER data after CLK $\uparrow$	
		0.5	—	—	0.5	—			SH/ $\overline{LD}$ high after CLK $\uparrow$	
Pulse width	t_w	5.0	—	—	6.0	—	ns		SH/ $\overline{LD}$ low	
		4.0	—	—	4.0	—			CLK H or L	

Operating Characteristics

- $C_L = 50\text{ pF}$

Item	Symbol	V_{CC} (V)	$T_a = 25^{\circ}\text{C}$			Unit	Test Conditions
			Min	Typ	Max		
Power dissipation capacitance	C_{PD}	3.3	—	36.1	—	pF	$f = 10\text{ MHz}$
		5.0	—	37.5	—		

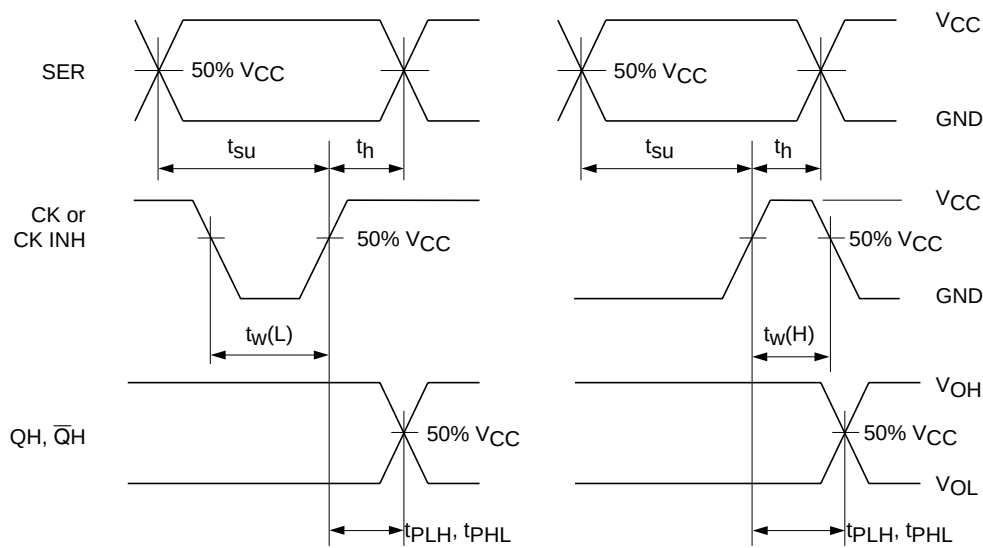
Test Circuit



Waveform

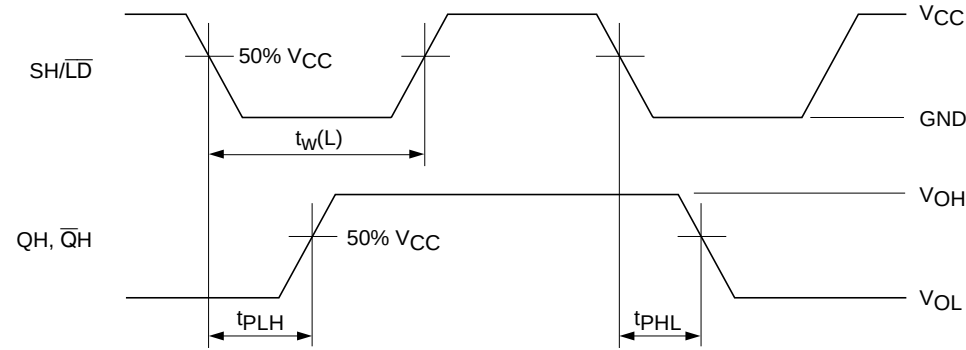
Waveform – 1

Sereial mode



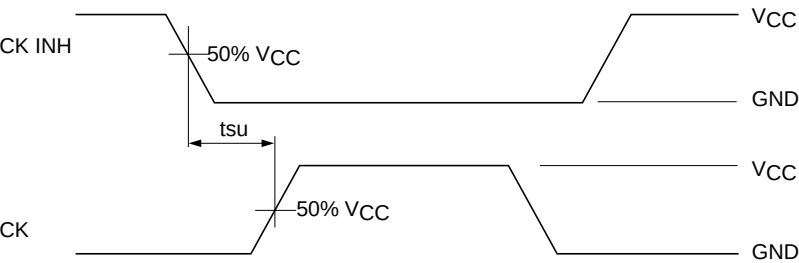
Waveform – 2

Parallel mode



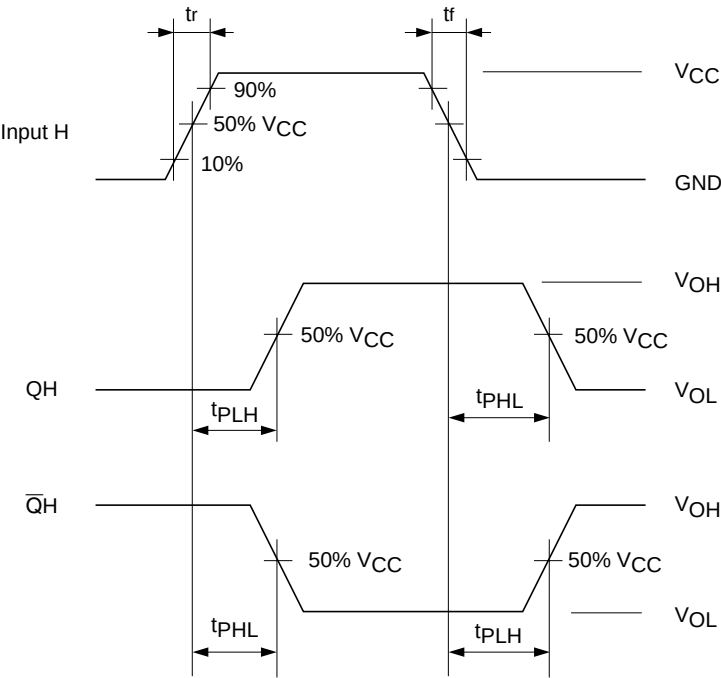
Waveform – 3

Sereial mode

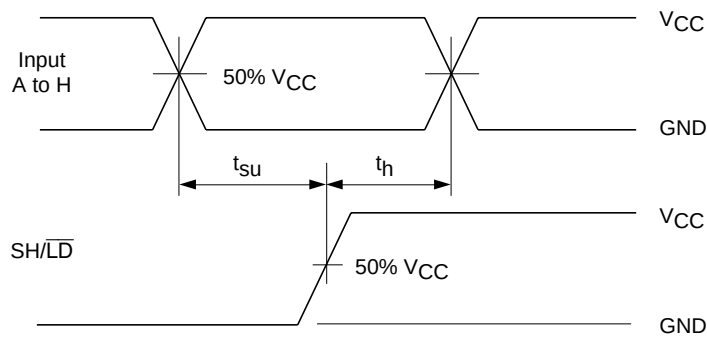


Waveform – 4

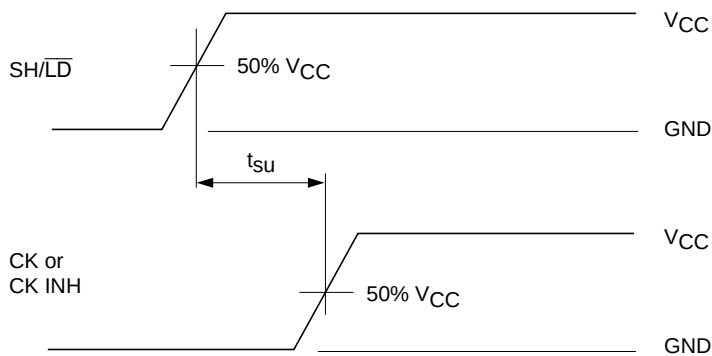
Parallel mode



Waveform – 5
Parallel mode

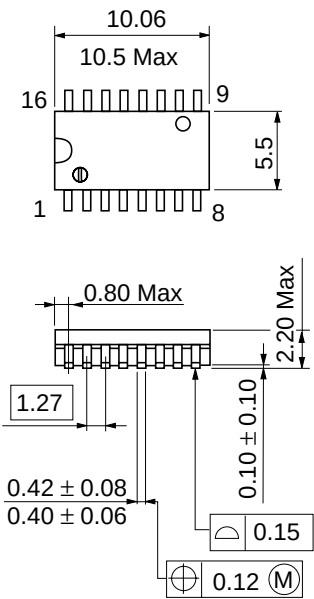
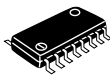
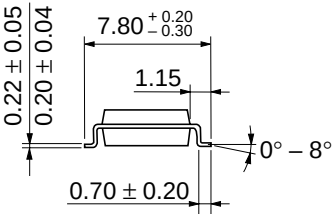


Waveform – 6
Serial mode



- Notes: 1. Input waveform: $PRR \leq 1 \text{ MHz}$, $Z_o = 50 \Omega$, $t_r \leq 3 \text{ ns}$, $t_f \leq 3 \text{ ns}$
2. The output are measured one at a time with one transition per measurement.

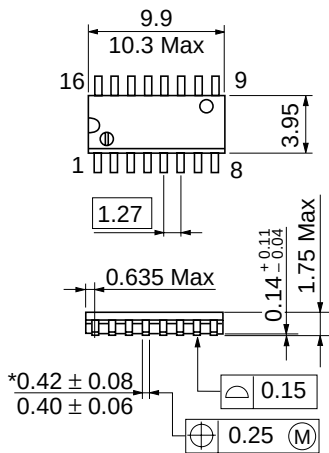
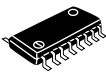
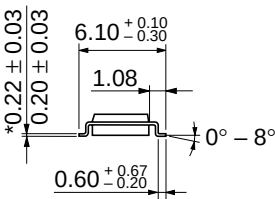
Package Dimensions



Dimension including the plating thickness
Base material dimension

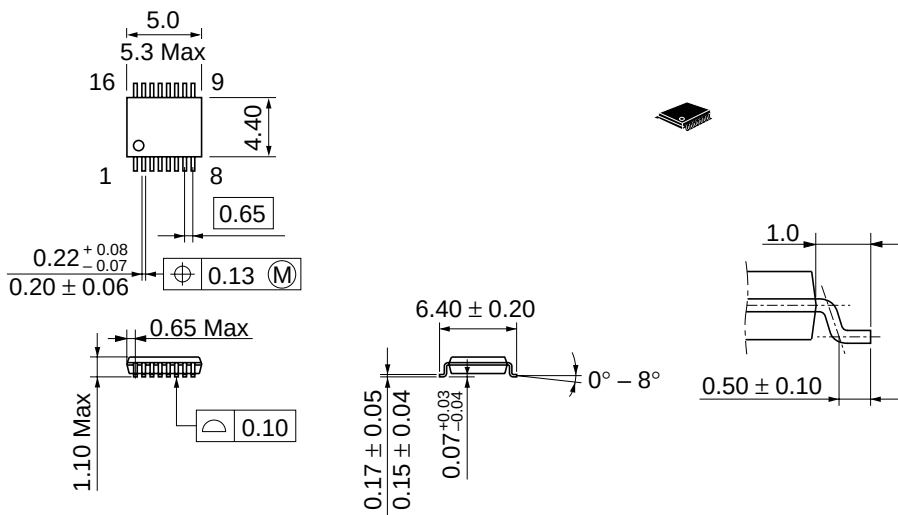
Hitachi Code	FP-16DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.24 g

Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g



Dimension including the plating thickness
Base material dimension

Hitachi Code	TTP-16DA
JEDEC	—
EIAJ	—
Weight (reference value)	0.05 g

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